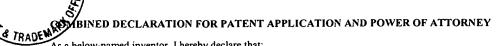
Attorney Docket No.: PATENT SSI-00501



As a below-named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated next to my name. I believe I am an original, first and joint inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: HIGH PRESSURE PROCESSING CHAMBER FOR SEMICONDUCTOR SUBSTRATE. The specification of which was filed July 24, 2001 as U.S. Patent Application Serial Number 09/912,844. I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims. I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, Section 1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code, § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed.

application on which priority is claimed	•			Priority Claim
Prior Foreign Application(s)				
	•			Yes No
<del></del>				
Number	Country		Day/Month/Year Filed	
I hereby claim the benefit under Title 35 matter of each of the claims of this appliparagraph of Title 35, United States Coc Regulations, § 1.56(a) which occurred b application:	ication is not disclosed le. 8 112. I acknowledge	in the prior United State e the duty to disclose m	es application in the manner aterial information as defin	r provided by the first ed in Title 37, Code of Federal
Application Serial No.		Filing Date	Status: Pa	tented, Pending, Abandoned
I hereby claim the benefit under Title 35	, United States Code, §	119(e) of any United S	tates provisional application	n(s) listed below:
60/220,883 Application Serial No.		July 26, 2000 Filing Date	<del></del>	
Application Serial No.		Fining Date		
60/283,132		April 10, 2001		
Application Serial No.		Filing Date		
I hereby appoint the following as my attand Trademark Office in connection the  Thomas B. Haverstock  Please direct all correspondence regarding Thomas B. Haver	rewith:  32,571   ng this application to th	Jonathan O. Owens		
HAVERSTOCK of 260 Sheridan Average Palo Alto, Califor	& OWENS LLP enue, Suite 420			
I hereby declare that all statements made believed to be true; and further that thes punishable by fine or imprisonment or b jeopardize the validity of the application	e statements were made ooth, under Section 100	with the knowledge that I of Title 18 of the Unit	at willful false statements a	nd the like so made are
Full Name of First Joint Inventor: Maxi	imilian A. Biberger			
Inventor's Signature:	1. 0.	2:16		10/19/01
Residence: 737-6 Loma Verde Avenue, Citizenship: German Post Office Address: 737-6 Loma Verd		A 94302		/ Date
Full Name of Second Joint Inventor: Fr	ederick Paul Layman	<u></u>		
Inventor's Signature:	Hor			10/29/0/
Residence: 433 Miwok Court, Fremont Citizenship: United States	A 94538		<del></del>	· Date
Post Office Address: 433 Miwok Court	Fremont, CA 94538			

PATENT SSI-00501

Inventor's Signature:

Residence: 1790 Chevalier Drive, San Jose, CA 95124

Citizenship: United States
Post Office Address: 1790 Chevalier Drive, San Jose, CA 95124